

BC177
BC177A
BC177B

**SILICON
PNP TRANSISTORS**



TO-18 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR BC177, BC177A, and BC177B are silicon PNP transistors designed for general purpose amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Peak Collector Current
Peak Base Current
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{CBO} 50
 V_{CEO} 45
 V_{EBO} 5.0
 I_C 100
 I_{CM} 200
 I_{BM} 200
 P_D 300
 T_J, T_{stg} -65 to +200
 Θ_{JA} 583.3

UNITS

V
V
V
mA
mA
mA
mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CBO}	$V_{CB}=20\text{V}$		1.0	15	nA
I_{CBO}	$V_{CB}=20\text{V}, T_A=150^\circ\text{C}$			10	μA
I_{EBO}	$V_{EB}=5.0\text{V}$			50	nA
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		75	300	mV
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=5.0\text{mA}$		250		mV
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		730		mV
$V_{BE(SAT)}$	$I_C=100\text{mA}, I_B=5.0\text{mA}$		850		mV
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$	600	650	750	mV
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC177)	125		500	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC177A)	125		260	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC177B)	240		500	
f_T	$V_{CE}=5.0\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100			MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		4.0	6.0	pF
NF	$V_{CE}=5.0\text{V}, I_C=200\mu\text{A}, f=1.0\text{kHz},$ $R_S=2.0\text{k}\Omega, B=200\text{Hz}$			10	dB

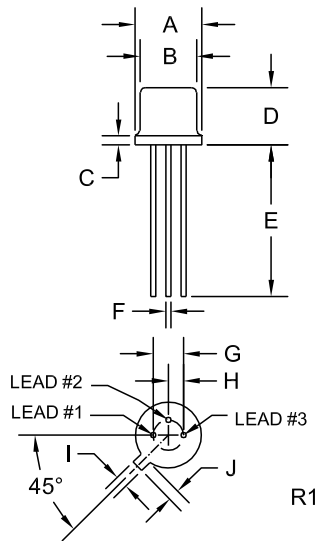
R0 (26-January 2016)

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TO-18 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS		MIN	MAX
	INCHES	MILLIMETERS		
A (DIA)	0.209	0.230	5.31	5.84
B (DIA)	0.178	0.195	4.52	4.95
C	-	0.030	-	0.76
D	0.170	0.210	4.32	5.33
E	0.500	-	12.70	-
F (DIA)	0.016	0.019	0.41	0.48
G (DIA)	0.100	2.54		
H	0.050	1.27		
I	0.036	0.046	0.91	1.17
J	0.028	0.048	0.71	1.22

TO-18 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

FULL PART NUMBER

R0 (26-January 2016)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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